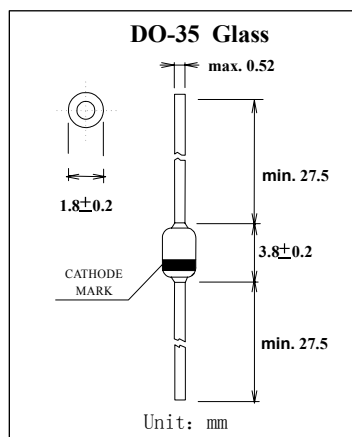


## 小信号肖特基二极管 Small Signal Schottky Diodes



## 特征 Features

- 反向漏电流小。Low reverse leakage
- 开关速度快。Fast switching speed
- 最大功率耗散500mW。Maximum power dissipation 500mW
- 高稳定性和可靠性。High stability and high reliability

## 机械数据 Mechanical Data

封装：DO-35 玻璃封装 Case: DO-35 Glass Case

极性：色环端为负极 Polarity: Color band denotes cathode end

安装位置：任意 Mounting Position: Any

极限值和温度特性  $T_A = 25^\circ\text{C}$  除非另有规定。Maximum Ratings & Thermal Characteristics Ratings at  $25^\circ\text{C}$  ambient temperature unless otherwise specified.

	符号 Symbols	1N4148	1N4448	单位 Unit
不重复峰值反向电压 Non-repetitive Peak Reverse Voltage	$V_{RM}$	100		V
反向峰值电压 peak repetitive Reverse Voltage	$V_{RRM}$	75		V
最大正向平均电流 Forward Continuous Current	$I_{FM}$	300	500	mA
平均整流输出电流 Average Rectified Output Current	$I_O$	150		mA
正向（不重复）浪涌电流 Non-Repetitive Peak Forward Surge Current	$I_{FSM}$	2.0		A
功率消耗 Power Dissipation	$P_d$	500		mW
典型热阻 Type Thermal Resistance	$R_{\theta JA}$	300		K/W
工作结温和存储温度 Operating junction and storage temperature range	$T_j, T_{STG}$	-50 --- +150		$^\circ\text{C}$

电特性  $T_A = 25^\circ\text{C}$  除非另有规定。Electrical Characteristics Ratings at  $25^\circ\text{C}$  ambient temperature unless otherwise specified.

	符号 Symbols	最小值 MIN.	最大值 MAX.	单位 Unit	测试条件 Test Condition
正向电压 Forward voltage	$V_{FM}$	---	1.0 0.62 1.0	V	$I_F = 10\text{mA}$ $I_F = 5.0\text{mA}$ $I_F = 100\text{mA}$
反向电流 Reverse current	$I_{RM}$	---	5.0 50 30 25	$\mu\text{A}$ $\mu\text{A}$ $\mu\text{A}$ nA	$V_R = 75\text{V}$ $V_R = 70\text{V}, T_j = 150^\circ\text{C}$ $V_R = 20\text{V}, T_j = 150^\circ\text{C}$ $V_R = 20\text{V}$
结电容 Junction capacitance	$C_j$	---		pF	$V_R = 0, f = 1.0\text{MHz}$
反向恢复时间 Reverse Recovery Time	$t_{rr}$	---	4.0	nS	$I_F = 10\text{mA} \rightarrow I_R = 1.0\text{mA}$ $V_R = 6.0\text{V}, R_L = 100\Omega$

## 特性曲线 Characteristic Curves

